

## Quad SPST CMOS Analog Switches

### Features

- Low On-Resistance: 50  $\Omega$
- Low Leakage: 80 pA
- Low Power Consumption: 0.2 mW
- Fast Switching Action— $t_{ON}$ : 150 ns
- Low Charge Injection—Q: -1 pC
- DG201A/DG202 Upgrades
- TTL/CMOS-Compatible Logic
- Single Supply Capability

### Benefits

- Less Signal Errors and Distortion
- Reduced Power Supply Requirements
- Faster Throughput
- Improved Reliability
- Reduced Pedestal Errors
- Simplifies Retrofit
- Simple Interfacing

### Applications

- Audio Switching
- Battery Powered Systems
- Data Acquisition
- Hi-Rel Systems
- Sample-and-Hold Circuits
- Communication Systems
- Automatic Test Equipment
- Medical Instruments

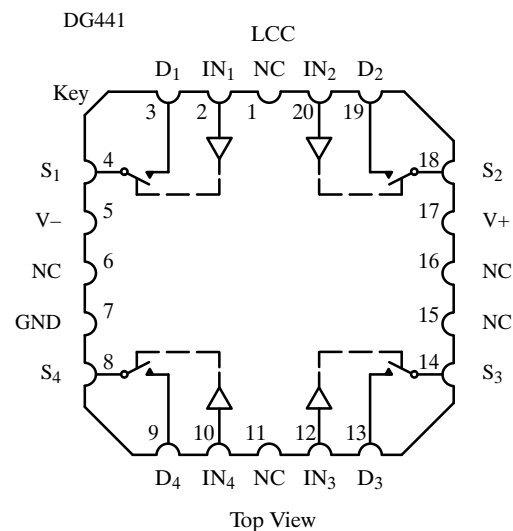
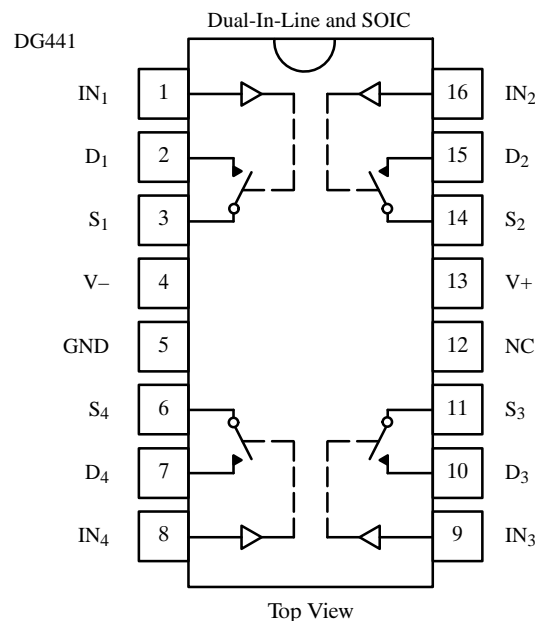
### Description

The DG441/442 monolithic quad analog switches are designed to provide high speed, low error switching of analog and audio signals. The DG441 has a normally closed function. The DG442 has a normally open function. Combining low on-resistance (50  $\Omega$ , typ.) with high speed ( $t_{ON}$  150 ns, typ.), the DG441/442 are ideally suited for upgrading DG201A/202 sockets. Charge injection has been minimized on the drain for use in sample-and-hold circuits.

To achieve high voltage ratings and superior switching performance, the DG441/442 are built on Siliconix's high-voltage silicon-gate process. An epitaxial layer prevents latchup.

Each switch conducts equally well in both directions when on, and blocks input voltages to the supply levels when off.

### Functional Block Diagram and Pin Configuration



Updates to this data sheet may be obtained via facsimile by calling Siliconix FaxBack, 1-408-970-5600. Please request FaxBack document #70053.

## Ordering Information and Truth Table

Ordering Information

Temp Range	Package	Part Number
-40 to 85°C	16-Pin Plastic DIP	DG441DJ
		DG442DJ
	16-Pin Narrow SOIC	DG441DY
		DG442DY
-55 to 125°C	16-Pin CerDIP	DG441AK
		DG441AK/883
		5962-9204101MEA
		DG442AK
		DG442AK/883
		5962-9204102MEA
	LCC-20	5962-9204101M2A
		5962-9204102M2A

Truth Table

Logic	DG441	DG442
0	ON	OFF
1	OFF	ON

Logic "0" ≤ 0.8 V  
 Logic "1" ≥ 2.4 V  
 Switches Shown for Logic "0" Input

## Absolute Maximum Ratings

V+ to V- .....	44 V	(DJ, DY Suffix) .....	-65 to 125°C
GND to V- .....	25 V	Power Dissipation (Package) <sup>b</sup>	
Digital Inputs <sup>a</sup> V <sub>S</sub> , V <sub>D</sub> .....	(V-) -2 V to (V+) +2 V	16-Pin Plastic DIP <sup>c</sup> .....	450 mW
	or 30 mA, whichever occurs first	16-Pin CerDIP <sup>d</sup> .....	900 mW
Continuous Current (Any Terminal) .....	30 mA	16-Pin Narrow Body SOIC <sup>d</sup> .....	900 mW
Current, S or D (Pulsed 1 ms, 10% duty cycle) .....	100 mA	LCC-20 <sup>d</sup> .....	1200 mW
Storage Temperature (AK Suffix) .....	-65 to 150°C	Notes:	
a. Signals on S <sub>X</sub> , D <sub>X</sub> , or IN <sub>X</sub> exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.			
b. All leads welded or soldered to PC Board.			
c. Derate 6 mW/°C above 75°C			
d. Derate 12 mW/°C above 25°C			

## Specifications <sup>NO TAG</sup> for Dual Supplies

Parameter	Symbol	Test Conditions Unless Otherwise Specified  V+ = 15 V, V- = -15 V V <sub>IN</sub> = 2.4 V, 0.8 V <sup>f</sup>	Temp <sup>b</sup>	Typ <sup>c</sup>	A Suffix -55 to 125°C		D Suffix -40 to 85°C		Unit
					Min <sup>d</sup>	Max <sup>d</sup>	Min <sup>d</sup>	Max <sup>d</sup>	
<b>Analog Switch</b>									
Analog Signal Range <sup>e</sup>	V <sub>ANALOG</sub>		Full		-15	15	-15	15	V
Drain-Source On-Resistance	r <sub>DS(on)</sub>	I <sub>S</sub> = -10 mA, V <sub>D</sub> = 8.5 V V+ = 13.5 V, V- = -13.5 V	Room Full	50		85 100		85 100	Ω
Switch Off Leakage Current	I <sub>S(off)</sub>	V+ = 16.5 V, V- = -16.5 V V <sub>D</sub> = ±15.5 V, V <sub>S</sub> = ∓15.5 V	Room Full	±0.01	-0.5 -20	0.5 20	-0.5 -5	0.5 5	nA
	I <sub>D(off)</sub>		Room Full	±0.01	-0.5 -20	0.5 20	-0.5 -5	0.5 5	
Channel On Leakage Current	I <sub>D(on)</sub>	V+ = 16.5 V, V- = -16.5 V V <sub>S</sub> = V <sub>D</sub> = 15.5 V	Room Full	±0.08	-0.5 -40	0.5 40	-0.5 -10	0.5 10	

## Specifications<sup>NO TAG</sup> for Dual Supplies (Cont'd)

Parameter	Symbol	Test Conditions Unless Otherwise Specified $V_+ = 15\text{ V}, V_- = -15\text{ V}$ $V_{IN} = 2.4\text{ V}, 0.8\text{ V}^f$	Temp <sup>b</sup>	Typ <sup>c</sup>	A Suffix -55 to 125°C		D Suffix -40 to 85°C		Unit	
					Min <sup>d</sup>	Max <sup>d</sup>	Min <sup>d</sup>	Max <sup>d</sup>		
<b>Digital Control</b>										
Input Current $V_{IN}$ Low	$I_{IL}$	$V_{IN}$ under test = 0.8 V All Other = 2.4 V	Full	-0.01	-500	500	-500	500	nA	
Input Current $V_{IN}$ High	$I_{IH}$	$V_{IN}$ under test = 2.4 V All Other = 0.8 V	Full	0.01	-500	500	-500	500		
<b>Dynamic Characteristics</b>										
Turn-On Time	$t_{ON}$	$R_L = 1\text{ k}\Omega, C_L = 35\text{ pF}$ $V_S = \square 10\text{ V}$ , See Figure 2	Room	150		250		250	ns	
Turn-Off Time	DG441		$t_{OFF}$	Room	90		120			120
	DG442		$t_{OFF}$	Room	110		210			210
Charge Injection <sup>e</sup>	Q	$C_L = 1\text{ nF}, V_S = 0\text{ V}$ $V_{gen} = 0\text{ V}, R_{gen} = 0\ \Omega$	Room	-1					pC	
Off Isolation <sup>e</sup>	OIRR	$R_L = 50\ \Omega, C_L = 5\text{ pF}$ $f = 1\text{ MHz}$	Room	60					dB	
Crosstalk (Channel-to-Channel)	$X_{TALK}$		Room	100						
Source Off Capacitance <sup>e</sup>	$C_{S(off)}$	$f = 1\text{ MHz}$	Room	4					pF	
Drain Off Capacitance <sup>e</sup>	$C_{D(off)}$		Room	4						
Channel On Capacitance <sup>e</sup>	$C_{D(on)}$		$V_{ANALOG} = 0\text{ V}$	Room	16					
<b>Power Supplies</b>										
Positive Supply Current	$I_+$	$V_+ = 16.5\text{ V}, V_- = -16.5\text{ V}$ $V_{IN} = 0\text{ or }5\text{ V}$	Full	15		100		100	$\mu\text{A}$	
Negative Supply Current	$I_-$		Room	-0.0001	-1		-1			
Ground Current	$I_{GND}$		Full	-15	-100		-100			

## Specifications<sup>NO TAG</sup> for Single Supply

Parameter	Symbol	Test Conditions Unless Otherwise Specified $V_+ = 12\text{ V}, V_- = 0\text{ V}$ $V_{IN} = 2.4\text{ V}, 0.8\text{ V}^f$	Temp <sup>b</sup>	Typ <sup>c</sup>	A Suffix -55 to 125°C		D Suffix -40 to 85°C		Unit
					Min <sup>d</sup>	Max <sup>d</sup>	Min <sup>d</sup>	Max <sup>d</sup>	
<b>Analog Switch</b>									
Analog Signal Range <sup>e</sup>	$V_{ANALOG}$		Full		0	12	0	12	V
Drain-Source On-Resistance	$r_{DS(on)}$	$I_S = -10\text{ mA}, V_D = 3\text{ V}, 8\text{ V}$ $V_+ = 10.8\text{ V}$	Room Full	100		160 200		160 200	$\Omega$
<b>Dynamic Characteristics</b>									
Turn-On Time	$t_{ON}$	$R_L = 1\text{ k}\Omega, C_L = 35\text{ pF}$ $V_S = 8\text{ V}$ , See Figure 2	Room	300		450		450	ns
Turn-Off Time	$t_{OFF}$		Room	60		200		200	
Charge Injection	Q	$C_L = 1\text{ nF}$ $V_{gen} = 6\text{ V}, R_{gen} = 0\ \Omega$	Room	2					pC

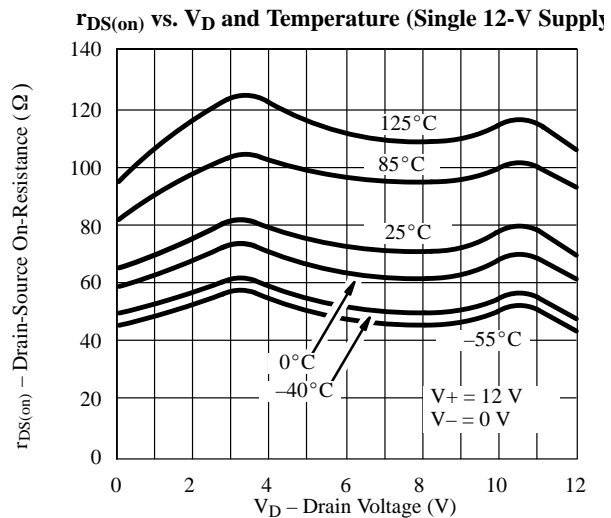
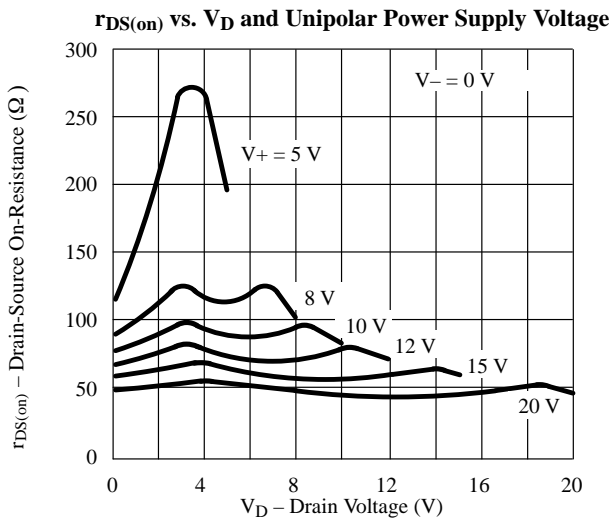
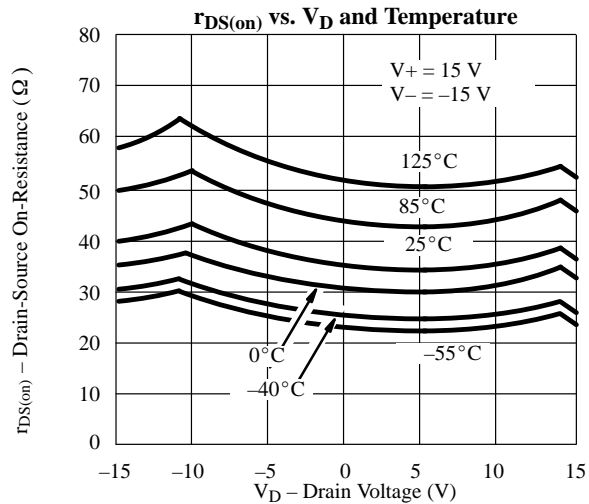
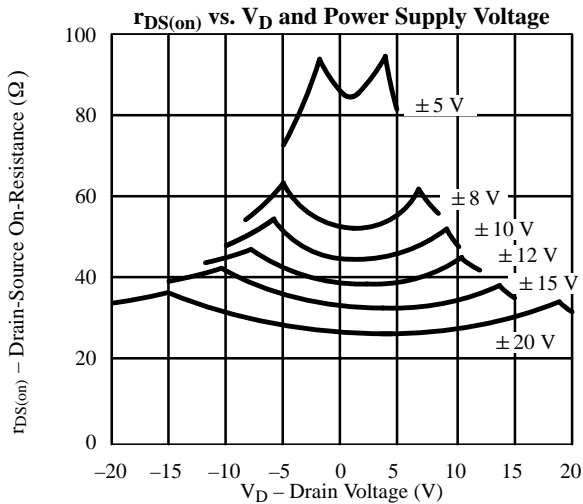
## Specifications<sup>NO TAG</sup> for Single Supply (Cont'd)

Parameter	Symbol	Test Conditions Unless Otherwise Specified $V_+ = 12\text{ V}, V_- = 0\text{ V}$ $V_{IN} = 2.4\text{ V}, 0.8\text{ V}^f$	Temp <sup>b</sup>	Typ <sup>c</sup>	A Suffix -55 to 125°C		D Suffix -40 to 85°C		Unit
					Min <sup>d</sup>	Max <sup>d</sup>	Min <sup>d</sup>	Max <sup>d</sup>	
<b>Power Supplies</b>									
Positive Supply Current	I+	$V_+ = 16.5\text{ V}, V_- = -16.5\text{ V}$ $V_{IN} = 0\text{ or }5\text{ V}$	Full	15		100		100	μA
Negative Supply Current	I-		Room Full	-0.0001	-1		-1		
Ground Current	I <sub>GND</sub>		Full	-15	-100		-100		

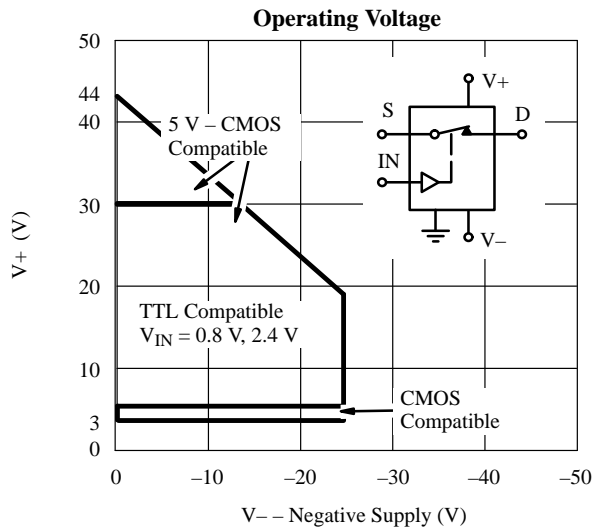
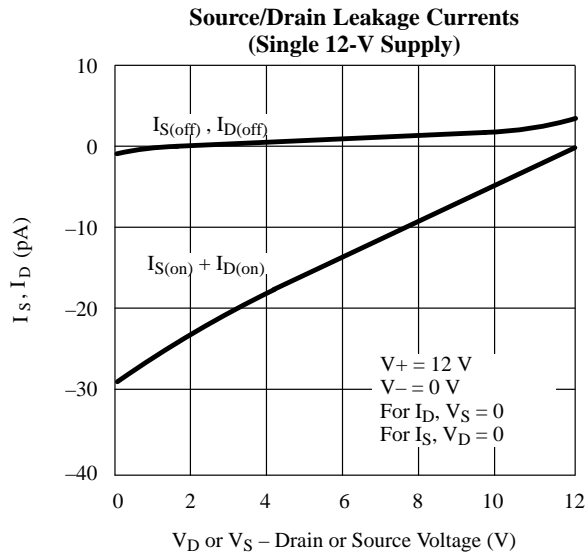
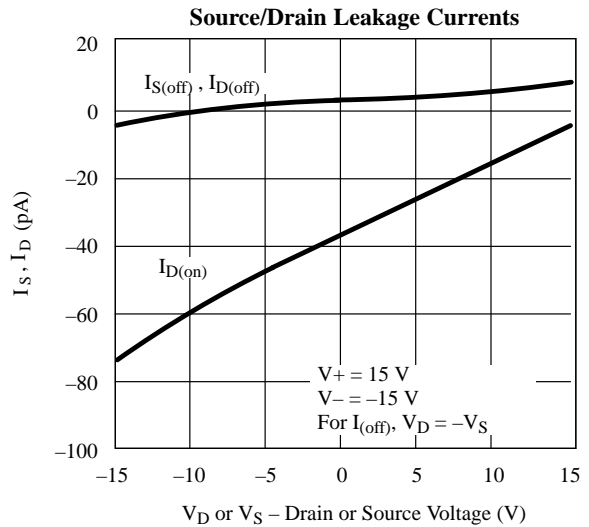
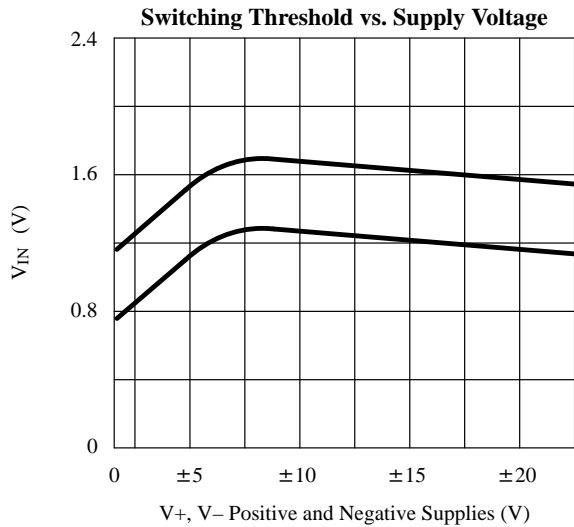
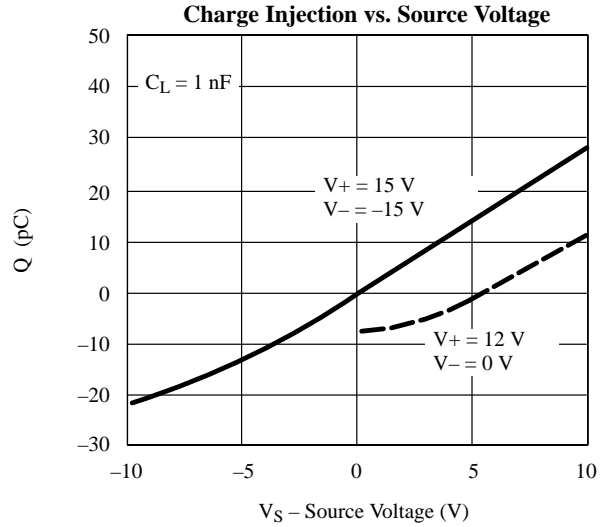
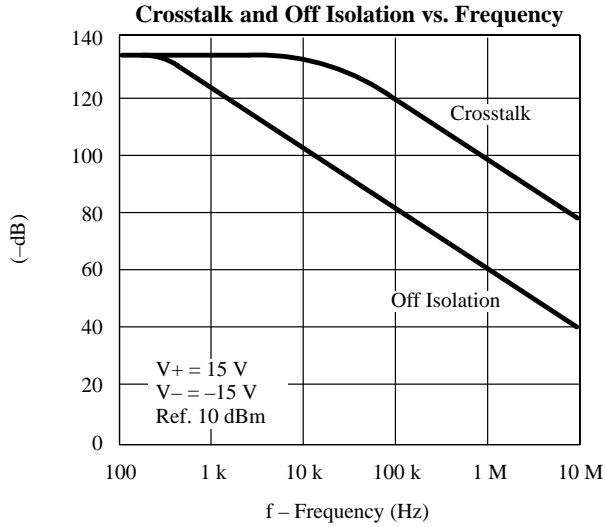
**Notes:**

- Refer to PROCESS OPTION FLOWCHART (Section 5 of the 1994 Data Book or FaxBack number 7103).
- Room = 25°C, Full = as determined by the operating temperature suffix.
- Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- Guaranteed by design, not subject to production test.
- $V_{IN}$  = input voltage to perform proper function.

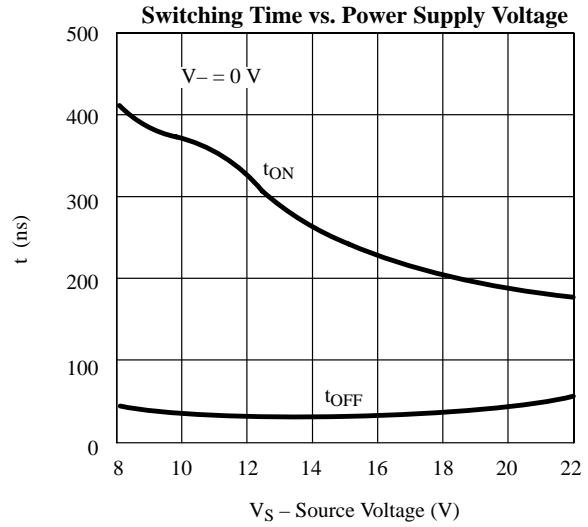
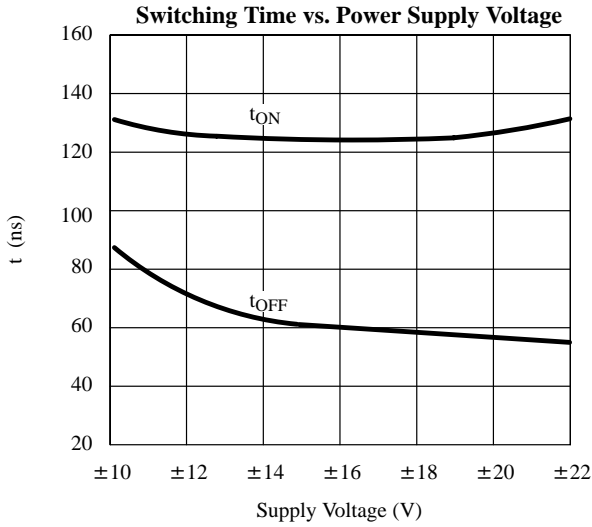
## Typical Characteristics



## Typical Characteristics (Cont'd)



## Typical Characteristics (Cont'd)



## Schematic Diagram (Typical Channel)

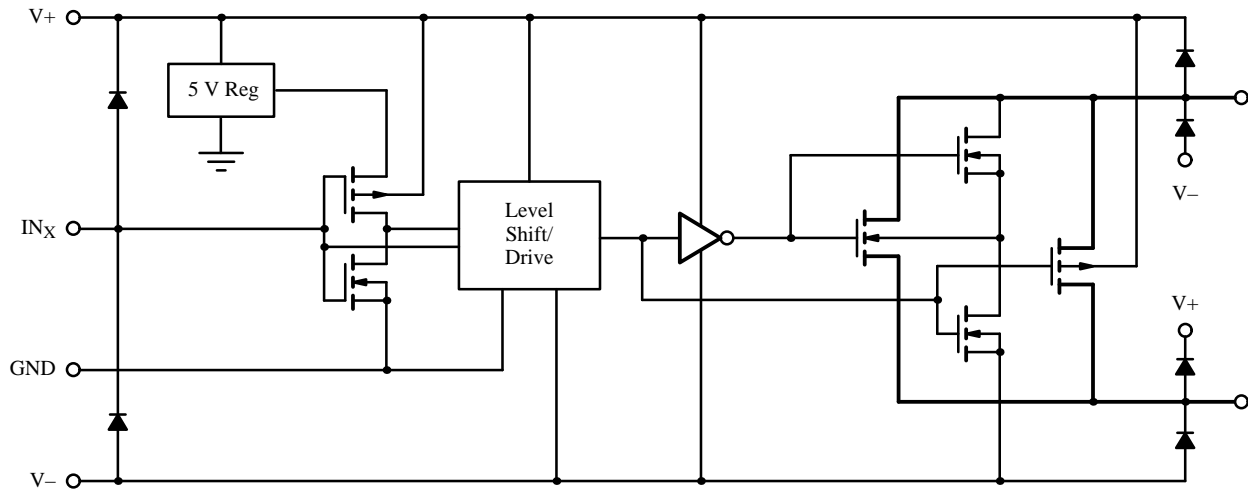
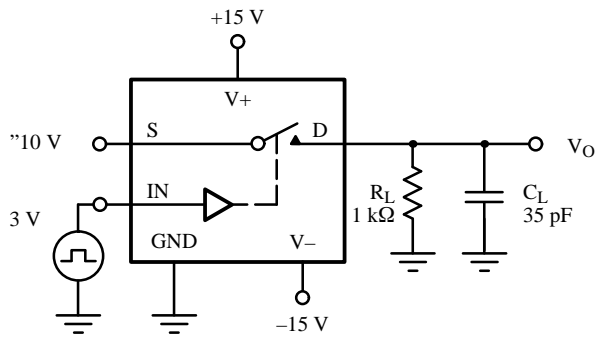
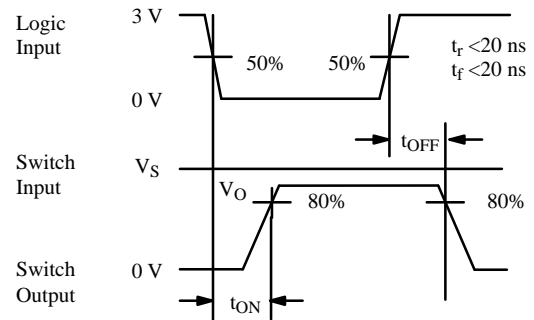


Figure 1.

## Test Circuits



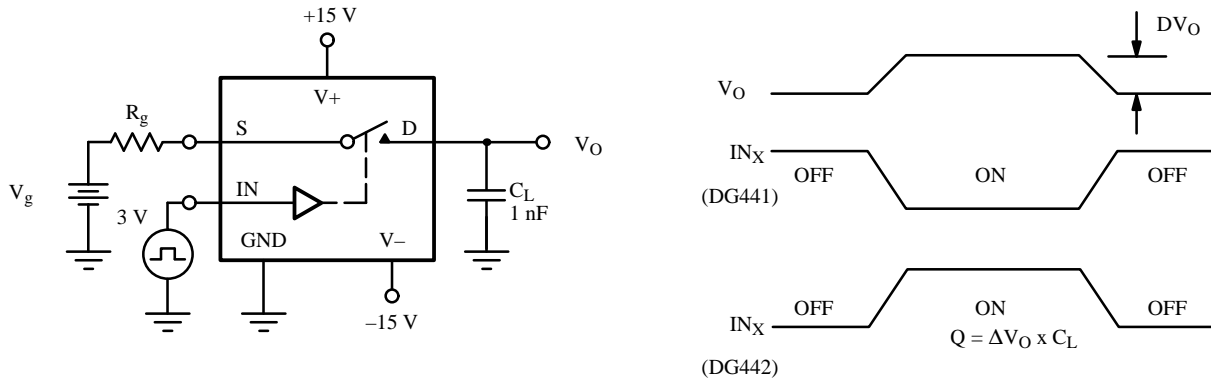
$C_L$  (includes fixture and stray capacitance)



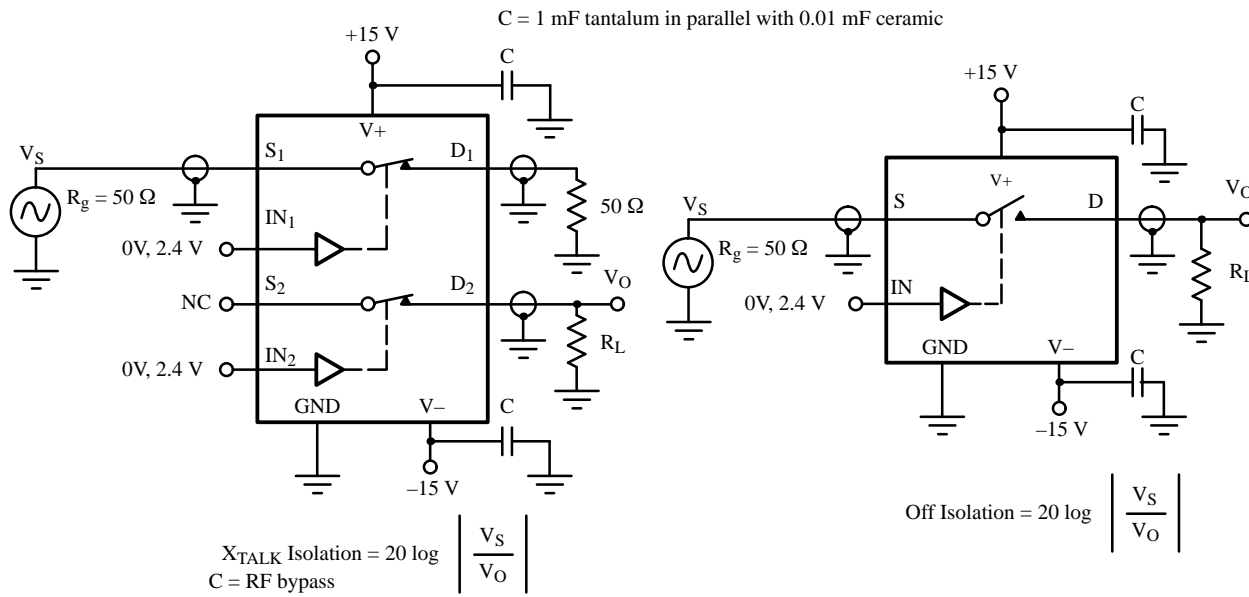
Note: Logic input waveform is inverted for DG442.

Figure 2. Switching Time

**Test Circuits (Cont'd)**

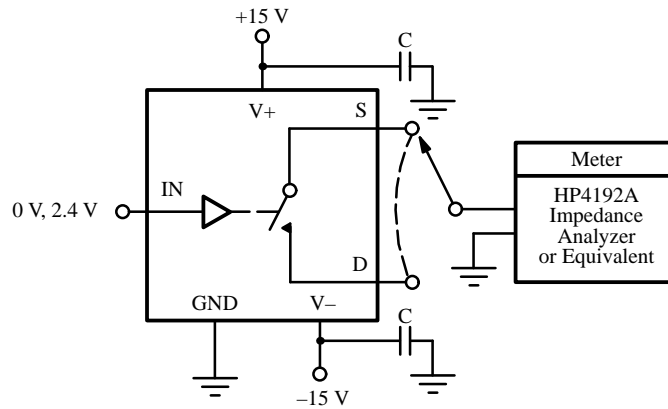


**Figure 3.** Charge Injection



**Figure 4.** Crosstalk

**Figure 5.** Off Isolation



**Figure 6.** Source/Drain Capacitances

## Applications

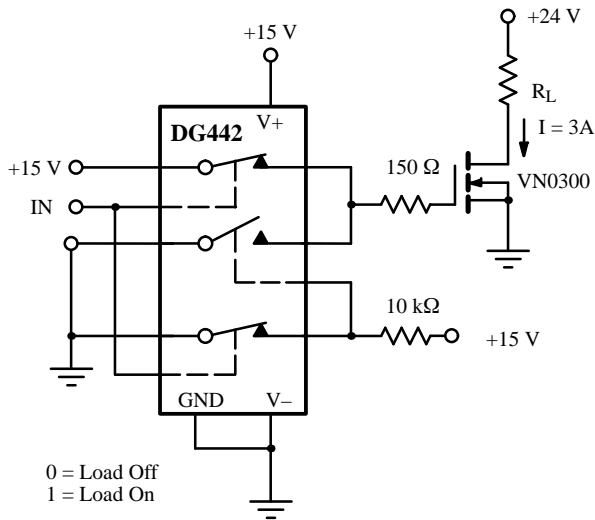


Figure 7. Power MOSFET Driver

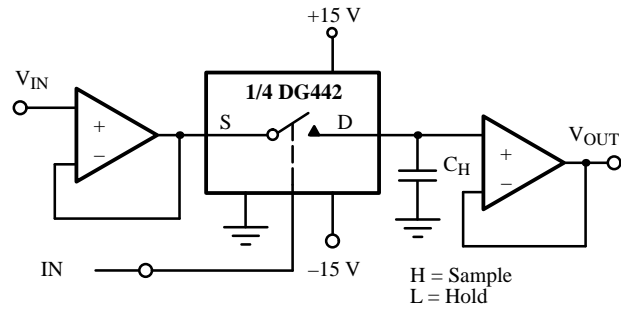
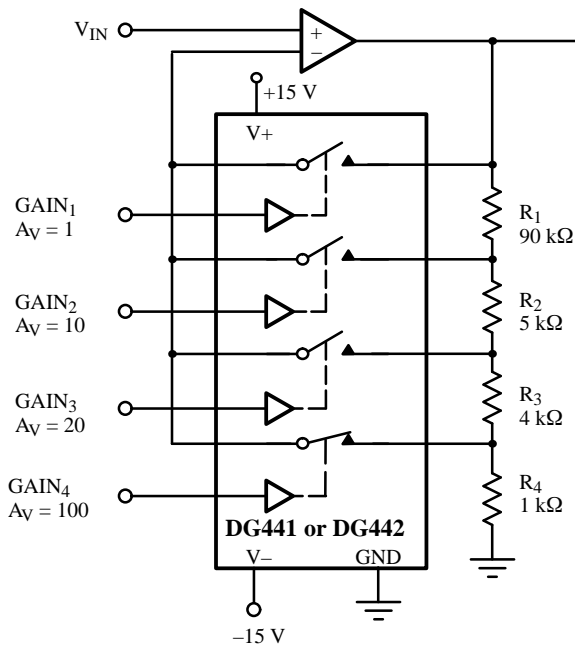


Figure 8. Open Loop Sample-and-Hold



Gain error is determined only by the resistor tolerance. Op amp offset and CMRR will limit accuracy of circuit.

With SW<sub>4</sub> Closed

$$\frac{V_{OUT}}{V_{IN}} = \frac{R_1 + R_2 + R_3 + R_4}{R_4} = 100$$

Figure 9. Precision-Weighted Resistor Programmable-Gain Amplifier